



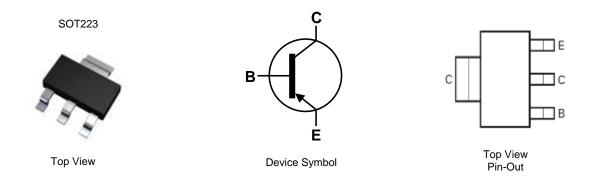
Features

- BV_{CEO} > -100V
- I_C = -5A High Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < -115mV @ -1A
- R_{CE(SAT)} = 75mΩ for a Low Equivalent On-Resistance
- h_{FE} Specified up to -10A for a High Gain Hold-Up
- Complementary NPN Type: FZT853
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

100V PNP MEDIUM POWER TRANSISTOR IN SOT223

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 3
- Weight: 0.112 grams (Approximate)



Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT953TA	AEC-Q101	FZT953	7	12	1,000
FZT953QTA	Automotive	FZT953	7	12	1,000

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

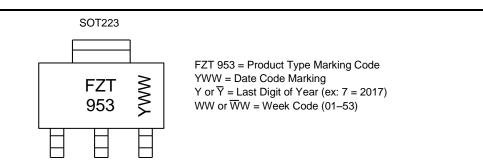
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-140	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ι _C	-5	A
Peak Pulse Current	Iсм	-10	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	ſ	3.0 24	W	
Linear Derating Factor	(Note 7)	P _D	1.6 12.8	mW /°C	
Thermal Desistance, lunction to Ambient	(Note 6)	R _{0JA}	42		
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	78	°C/W	
Thermal Resistance Junction to Lead	(Note 8)	R _{θJL}	8.84		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class	
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B	
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С	

Notes: 6. For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

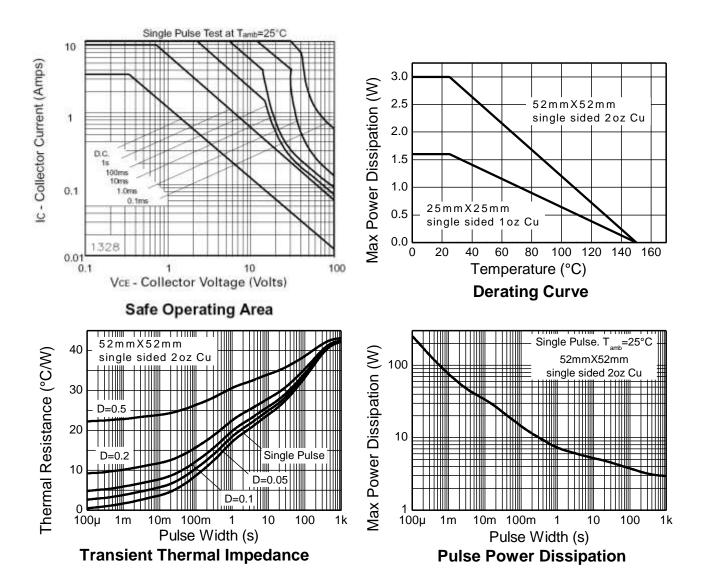
7. Same as Note 6, except the device is surface mounted on 25mm x 25mm with 1oz copper.

8. Thermal resistance from junction to solder-point (at the end of the collector lead).

9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



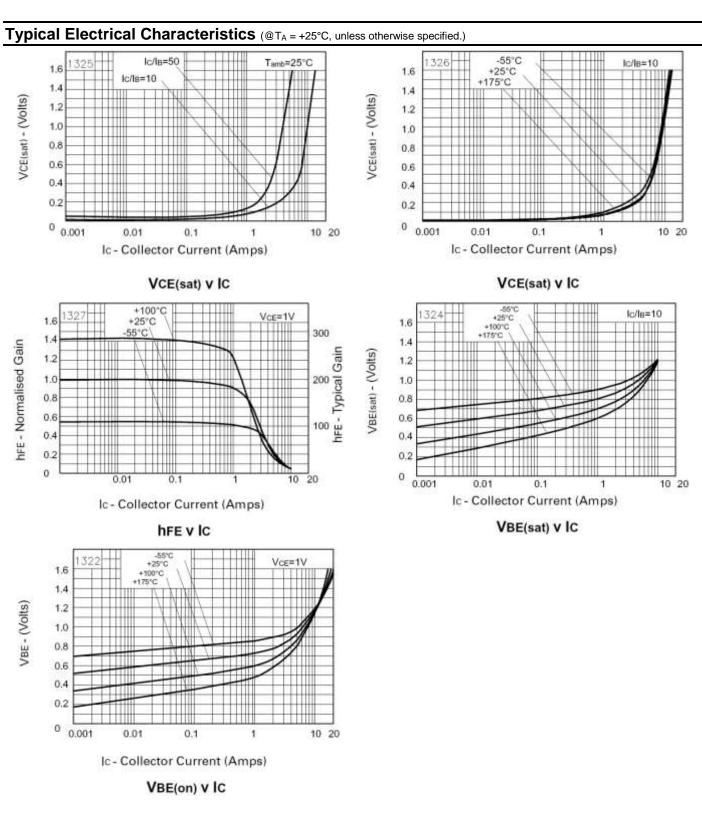


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition		
Collector-Base Breakdown Voltage	BV _{CBO}	-140	-170	—	V	I _C = -100μA		
Collector-Emitter Breakdown Voltage (Note 10)	BVCER	-140	-170	—	V	$I_C = -1\mu A, R_B \le 1k\Omega$		
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-100	-120	—	V	$I_{\rm C} = -1 {\rm mA}$		
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8	_	V	I _E = -100μA		
Collector Cutoff Current			<-1	-50	nA	V _{CB} = -100V		
	I _{CBO}	_	—	-1	μA	$V_{CB} = -100V, T_A = +100^{\circ}C$		
Collector Cutoff Current	ICER		<-1	-50	nA	$V_{CE} = -100V, R \le 1k\Omega$		
	-	_	—	-1	μA	$V_{CE} = -100V, T_A = +100^{\circ}C$		
Emitter Cutoff Current	I _{EBO}	—	<-1	-10	nA	$V_{EB} = -6V$		
	hfe	100	200	-		$I_{C} = -10mA, V_{CE} = -1V$		
		100	200	300	—	$I_{C} = -1A, V_{CE} = -1V$		
DC Current Transfer Static Ratio (Note 10)		50	90	_		$I_{C} = -3A, V_{CE} = -1V$		
		30	50	_		I _C = -4A, V _{CE} = -1V		
		_	15	_		I _C = -10A, V _{CE} = -1V		
	V _{CE(SAT)}	_	-20	-50		$I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -10 {\rm mA}$		
Collector Emitter Coturation Valence (Nate 10)		_	-90	-115		$I_{\rm C} = -1$ A, $I_{\rm B} = -100$ mA		
Collector-Emitter Saturation Voltage (Note 10)		_	-160	-220	mV	$I_{\rm C} = -2A, I_{\rm B} = -200 {\rm mA}$		
		_	-300	-420		$I_{\rm C} = -4A, I_{\rm B} = -400 \text{mA}$		
Base-Emitter Saturation Voltage (Note 10)	V _{BE(SAT)}	_	-1,010	-1,170	mV	$I_{\rm C} = -4A, I_{\rm B} = -400 \text{mA}$		
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(ON)}	_	-925	-1,160	mV	I _C = -4A, V _{CE} = -1V		
Transitional Frequency	f _T	_	125	_	MHz	$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V}, $ f = 50MHz		
Output Capacitance	C _{OBO}		65		pF	V _{CB} = -10V, f = 1MHz		
Qualitatian Time	ton		110	_		$V_{CC} = -10V, I_C = -2A,$		
Switching Time	tOFF	—	460	—	ns	$-I_{B1} = I_{B2} = -200 \text{mA}$		

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



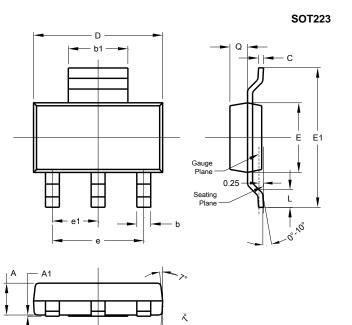


FZT953



Package Outline Dimensions

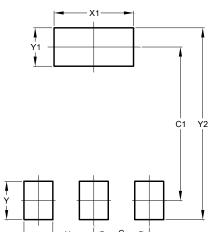
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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FZT953 Datasheet Number: DS35942 Rev. 5 - 2

SOT223



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